TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (π-MOSII<sup>-5</sup>)

# 2SK1119

#### DC-DC Converter and Motor Drive Applications

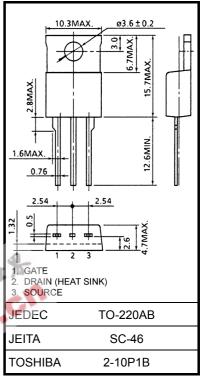
Unit: mm

 $\begin{array}{ll} \bullet & \text{Low drain-source ON resistance} & : \text{RDS (ON)} = 3.0 \ \Omega \ (\text{typ.}) \\ \bullet & \text{High forward transfer admittance} & : |Y_{fs}| = 2.0 \ S \ (\text{typ.}) \\ \bullet & \text{Low leakage current} & : I_{DSS} = 300 \ \mu\text{A (max)} \ (\text{V}_{DS} = 800 \ \text{V}) \\ \end{array}$ 

• Enhancement mode  $V_{th} = 1.5 \sim 3.5 \text{ V (V}_{DS} = 10 \text{ V, I}_{D} = 1 \text{ mA}$ 

### **Absolute Maximum Ratings (Ta = 25°C)**

Characteris	stics	Symbol	Rating	Unit	
Drain-source voltage		$V_{DSS}$	1000	V	
Drain-gate voltage (Ro	<sub>SS</sub> = 20 kΩ)	$V_{DGR}$	1000	V	
Gate-source voltage		$V_{GSS}$	±20	V	
Drain current	DC (Note 1)	ΙD	4		
	Pulse (Note 1)	I <sub>DP</sub>	12	_^0	
Drain power dissipation	n (Tc = 25°C)	PD	100	W	
Channel temperature		T <sub>ch</sub>	150	°C	
Storage temperature ra	ange	T <sub>stg</sub>	<b>−5</b> 5~150	°C	



Weight: 2.0 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

#### **Thermal Characteristics**

Characteristics	Symbol	Max	Unit
Thermal resistance, channel to case	R <sub>th (ch-c)</sub>	1.25	°C / W
Thermal resistance, channel to ambient	R <sub>th (ch-a)</sub>	83.3	°C / W

Note 1: Ensure that the channel temperature does not exceed 150°C.

This transistor is an electrostatic-sensitive device.

Please handle with caution.



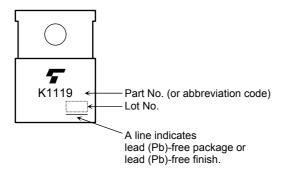
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Charac	eteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage cu	rrent	I <sub>GSS</sub>	V <sub>GS</sub> = ±20 V, V <sub>DS</sub> = 0 V	_	_	±100	nA
Drain cut-off cu	rrent	I <sub>DSS</sub>	V <sub>DS</sub> = 800 V, V <sub>GS</sub> = 0 V	-	_	300	μΑ
Drain-source br voltage	eakdown	V <sub>(BR)</sub> DSS	I <sub>D</sub> = 10 mA, V <sub>GS</sub> = 0 V	1000	_	_	V
Gate threshold v	oltage	V <sub>th</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 1 mA	1.5	_	3.5	V
Drain-source Ol	N resistance	R <sub>DS</sub> (ON)	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 2 A	_	3.0	3.8	Ω
Forward transfer	admittance	Y <sub>fs</sub>	V <sub>DS</sub> = 20 V, I <sub>D</sub> = 2 A	1.0	2.0	_	S
Input capacitano	е	C <sub>iss</sub>		_	700	_	
Reverse transfer	verse transfer capacitance $C_{rss}$ $V_{DS} = 25 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$		V <sub>DS</sub> = 25 V, V <sub>GS</sub> = 0 V, f = 1 MHz	_	55	_	pF
Output capacitance		Coss	]		100	_	
Switching time	Rise time	t <sub>r</sub>	$V_{GS} = V_{OUT}$ $V_{GS} = V_{OUT}$ $R_{L}$ $= 200 \Omega$	_	18	_	
	Turn-on time	t <sub>on</sub>		_	30	_	
	Fall time	t <sub>f</sub>	4 4 4 6	_	12	_	ns
	Turn-off time	t <sub>off</sub>	$V_{\mathrm{DD}} = 400 \mathrm{V}$ Duty $\leq 1\%$ , $t_{\mathrm{W}} = 10 \mu\mathrm{s}$	0	70	_	
Total gate charge (Gate-source plus gate-drain)		Qg	38 37		60		
Gate-source charge		$Q_{gs}$	$V_{DD} \approx 400 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 6 \text{ A}$	_	35	_	nC
Gate-drain ("miller") charge		Q <sub>gd</sub>		_	25	_	

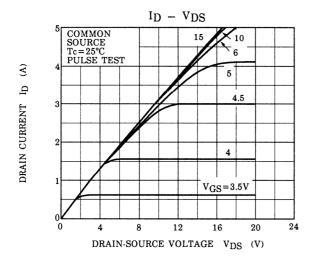
## Source-Drain Ratings and Characteristics (Ta = 25°C)

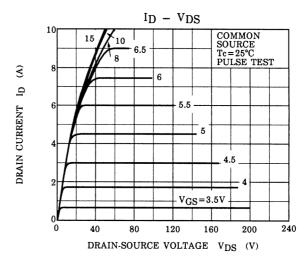
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Continuous drain reverse current (Note 1)	I <sub>DR</sub>	_	_	_	4	Α
Pulse drain reverse current (Note 1)	I <sub>DRP</sub>	_	-	_	12	Α
Forward voltage (diode)	V <sub>DSF</sub>	I <sub>DR</sub> = 4 A, V <sub>GS</sub> = 0 V	1	_	-1.9	V

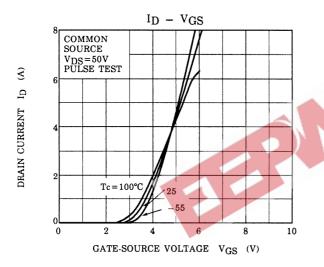
## Marking

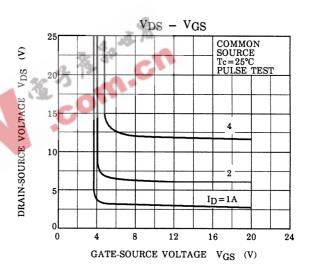


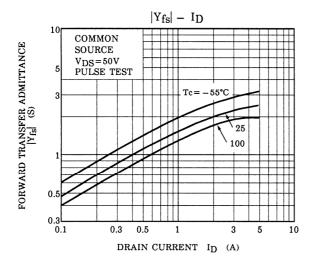
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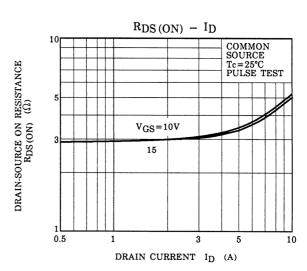




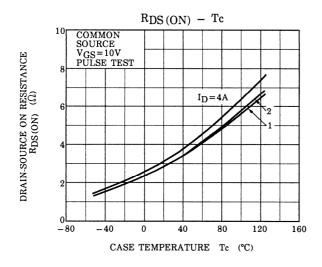


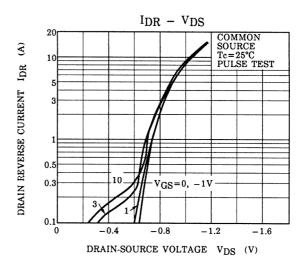


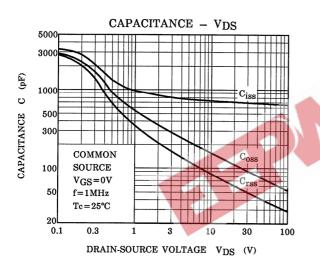


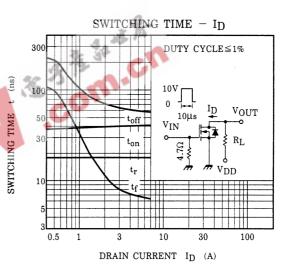


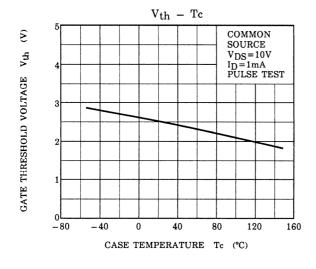
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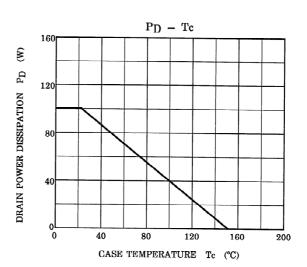


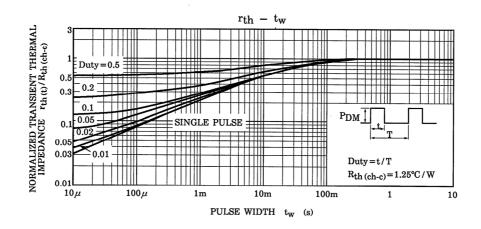


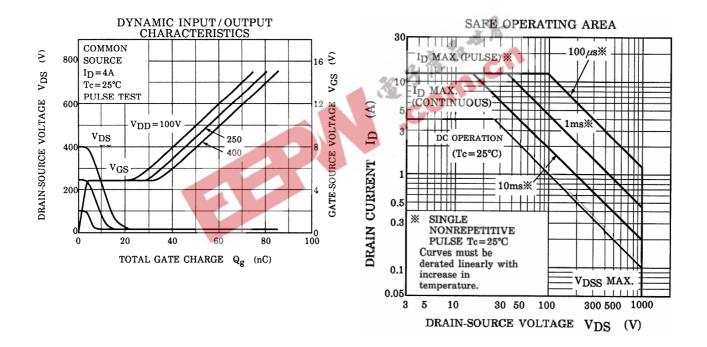












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